Diode Semiconductor Device - Page 1 of 1



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Metal	
Overall Length:	
0.570 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.215 inches	and 0.235 inches
Function For Which [esigned:
Transient suppressor	
End Application:	
Radar bomb scoring se	t, an/tpq-43
Joint Electronic Devi	e Engineering Council/jedec/case Outline Designation:
Do-13	
Electrode Internally-e	ectrically Connected To Case:
Cathode	
Mounting Method:	
Terminal	
Semiconductor Mater	ial:
Silicon	
Voltage Rating In Vol	s Per Characteristic:
114.0 breakdown volta	ge, dc and 126.0 breakdown voltage, dc
Current Rating Per C	aracteristic:
200.00 amperes forwa	d current, average preset and 5.00 microamperes forward current, average peak
Power Rating Per Cha	racteristic:
1.0 watts small-signal i	nput power, common-collector horsepower metric
Maximum Operating	empurature Per Measurement Point:
175.0 degrees celsius	ambient air
Test Data Document:	
81349-mil-s-19500 spe	cification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes comr	nercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and per	ormance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Q	Jantity:
2 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/500	government specification
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	
5	